



EV317135827

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 09/292,132
Filing Date April 14, 1999
Inventor Salman Akram et al.
Assignee Micron Technology, Inc.
Group Art Unit 2812
Examiner Savitri Mulpuri
Attorney's Docket No. MI22-1171
Title: Methods of Forming a Transistor Gate

EXAMINER INTERVIEW SUMMARY OF JULY 16, 2003

To: Commissioner for Patents
Alexandria, VA 22313

From: D. Brent Kenady
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Applicant's representatives held an interview with Examiner Mulpuri on July 17, 2003. Applicant's representatives would like to thank Examiner Mulpuri for her time and attention to this matter.

Independent claims 55, 62, and 68 and respective rejections were discussed. No agreement was reached.

Moreover, claims 84-87 were not presented with any rejections in the most recent office action (paper no. 29). Regarding such, Applicant respectfully

07/31/2003 MGE BREM1 00000113 09292132


01 FC:1201
02 FC:1202

84.00 OP
72.00 OP

requests either allowance of such claims or a new **non-final** office action to allow Applicant the opportunity to address the new rejections.

Respectfully submitted,

Dated: 7-28-03

By: 
D. Brent Kenady
Reg. No. 40,045